

STU13N60M2

Request a Quote

STU13N60M2 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



STU13N60M2 Specifications

Manufacturer Part Number	STU13N60M2
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	MDmesh? II Plus
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	11A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	580pF @ 100V
Vgs (Max)	±25V
FET Feature	-
Power Dissipation (Max)	110W (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 5.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	IPAK (TO-251)
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors?

STU13N60M2 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

STU13N60M2 Payment Methods



STU13N60M2 Shipping Methods



If you have any question about STU13N60M2, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com